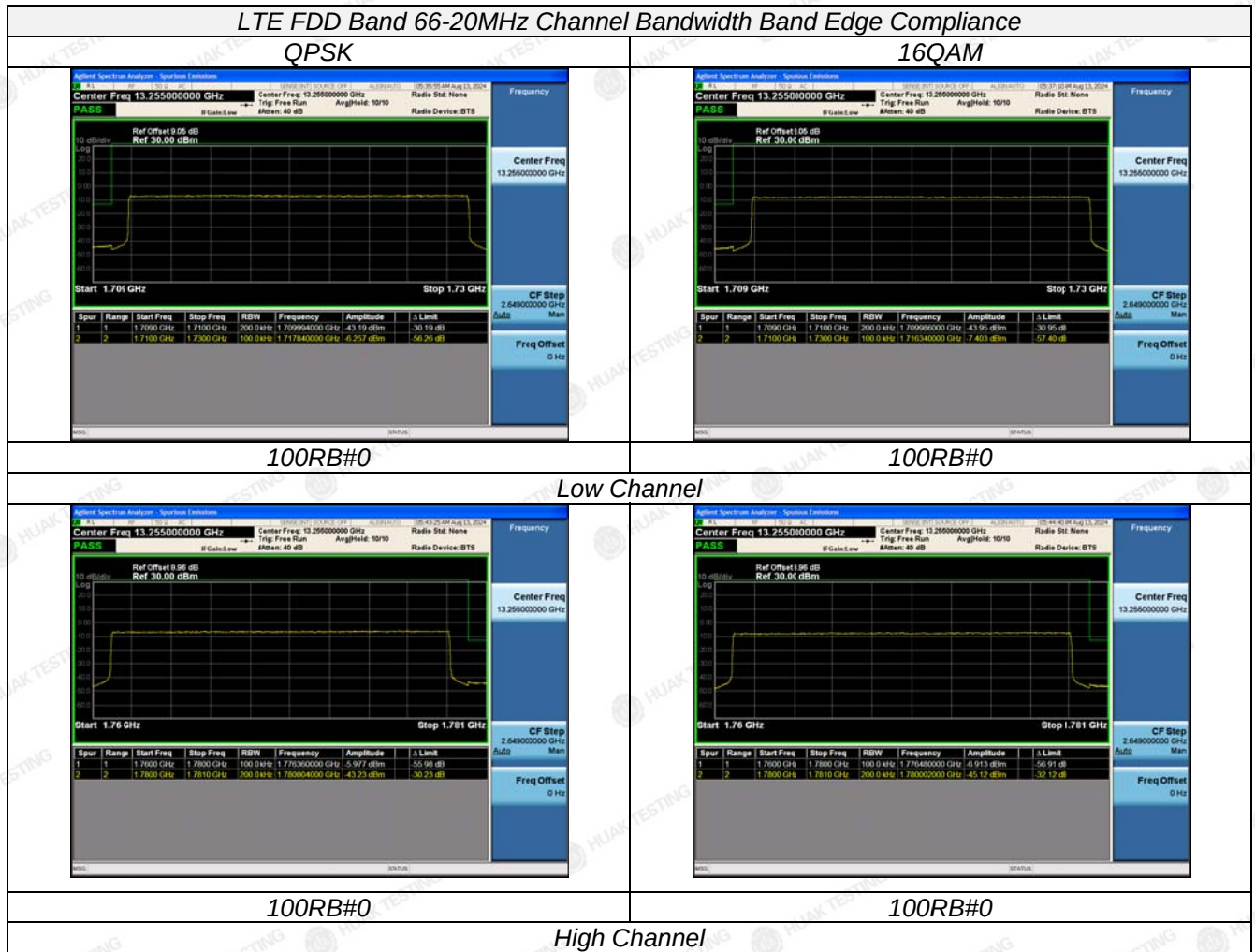






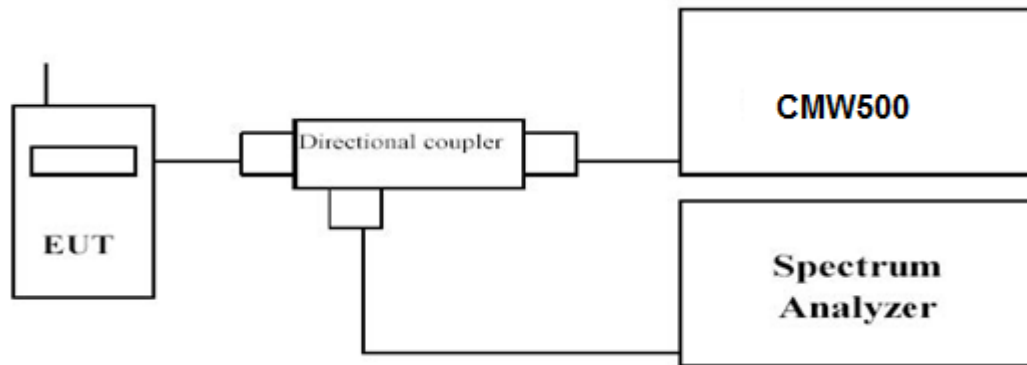
3.5 Spurious Emission

LIMIT

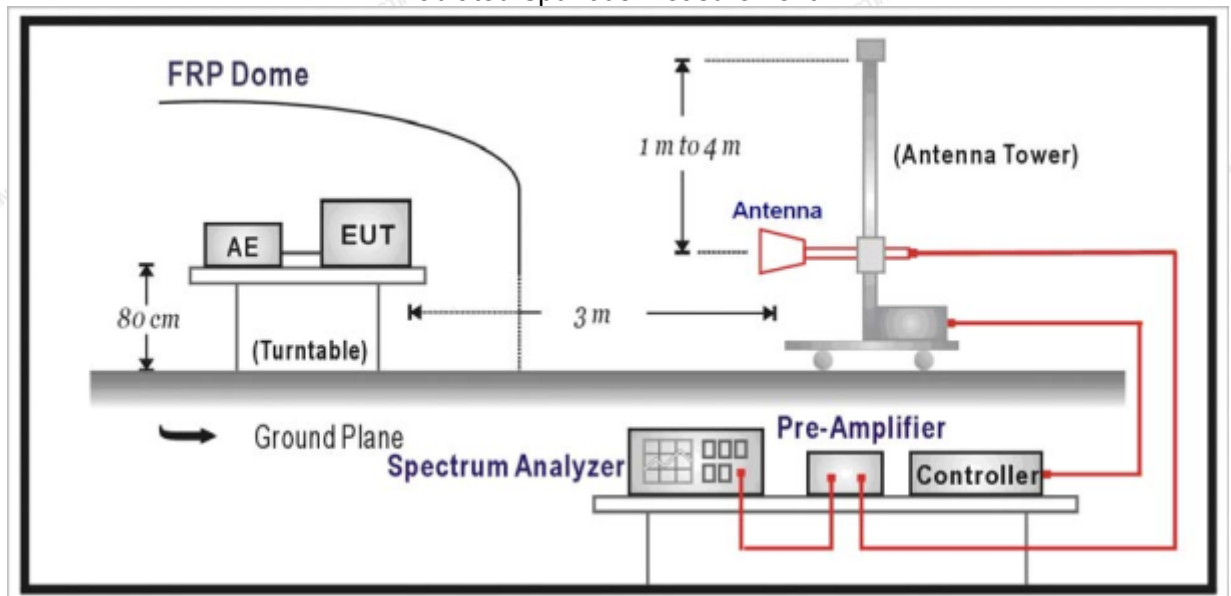
According to §27.53 (h): For operations in the 1710–1755 MHz and 2110–2155 MHz bands, the power of any emission outside a licensee's frequency block shall be attenuated below the transmitter power (P) by at least $43 + 10 \log_{10}(P)$ dB.

TEST CONFIGURATION

Conducted Spurious Measurement:



Radiated Spurious Measurement:



TEST PROCEDURE

The EUT was setup according to EIA/TIA 603D.

Conducted Spurious Measurement:

- Place the EUT on a bench and set it in transmitting mode.
- Connect a low loss RF cable from the antenna port to a spectrum analyzer and CMW500 by a Directional Coupler.
- EUT Communicate with CMW500, then select a channel for testing.
- Add a correction factor to the display of spectrum, and then test.
- The resolution bandwidth of the spectrum analyzer was set sufficient scans were taken to show the out of band Emission if any up to 10^{th} harmonic.



f. Please refer to following tables for test antenna conducted emissions.

Working Frequency	Sub range (GHz)	RBW	VBW	Sweep time (s)
LTE FDD Band 66	0.000009~0.000015	1KHz	3KHz	Auto
	0.000015~0.03	10KHz	30KHz	Auto
	0.03~26.5	1 MHz	3 MHz	Auto

Radiated Spurious Measurement:

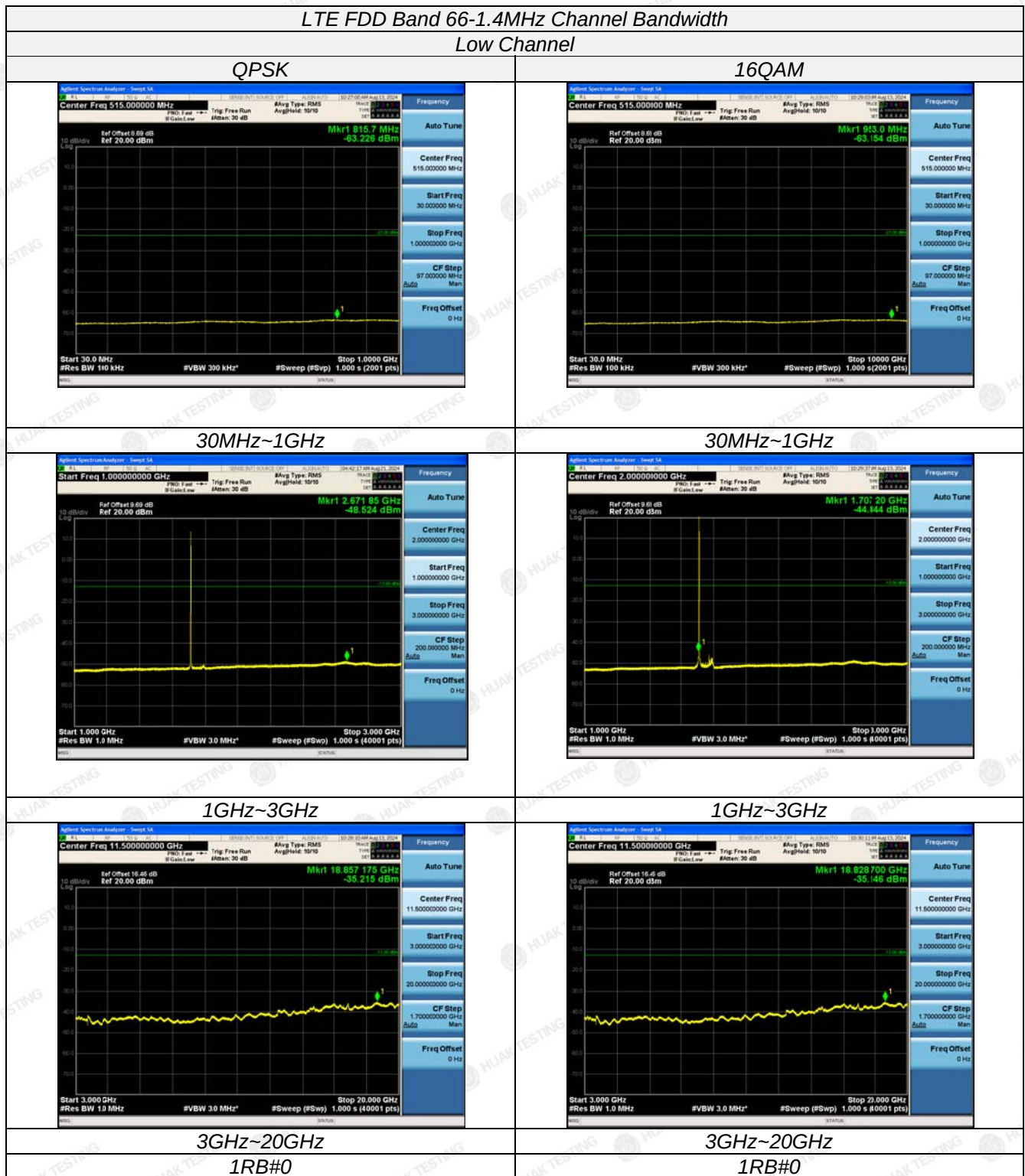
- The EUT shall be placed at the specified height on a support, and in the position closest to normal use as declared by provider.
- The test antenna shall be oriented initially for vertical polarization and shall be chosen to correspond to the frequency of the transmitter.
- The output of the test antenna shall be connected to the measuring receiver.
- The transmitter shall be switched on and the measuring receiver shall be tuned to the frequency of the transmitter under test.
- The test antenna shall be raised and lowered through the specified range of height until a maximum signal level is detected by the measuring receiver.
- The transmitter shall then be rotated through 360° in the horizontal plane, until the maximum signal level is detected by the measuring receiver.
- The test antenna shall be raised and lowered again through the specified range of height until a maximum signal level is detected by the measuring receiver.
- The maximum signal level detected by the measuring receiver shall be noted.
- The transmitter shall be replaced by a substitution antenna.
- The substitution antenna shall be orientated for vertical polarization and the length of the substitution antenna shall be adjusted to correspond to the frequency of the transmitter.
- The substitution antenna shall be connected to a calibrated signal generator.
- If necessary, the input attenuator setting of the measuring receiver shall be adjusted in order to increase the sensitivity of the measuring receiver.
- The test antenna shall be raised and lowered through the specified range of height to ensure that the maximum signal is received.
- The input signal to the substitution antenna shall be adjusted to the level that produces a level detected by the measuring receiver, that is equal to the level noted while the transmitter radiated power was measured, corrected for the change of input attenuator setting of the measuring receiver.
- The measurement shall be repeated with the test antenna and the substitution antenna orientated for horizontal polarization.
- The measure of the effective radiated power is the larger of the two levels recorded at the input to the substitution antenna, corrected for gain of the substitution antenna if necessary.
- The resolution bandwidth of the spectrum analyzer was set at 100 kHz for Part 22 and 1MHz for Part 24. The frequency range was checked up to 10th harmonic.
- Test site anechoic chamber refer to ANSI C63.

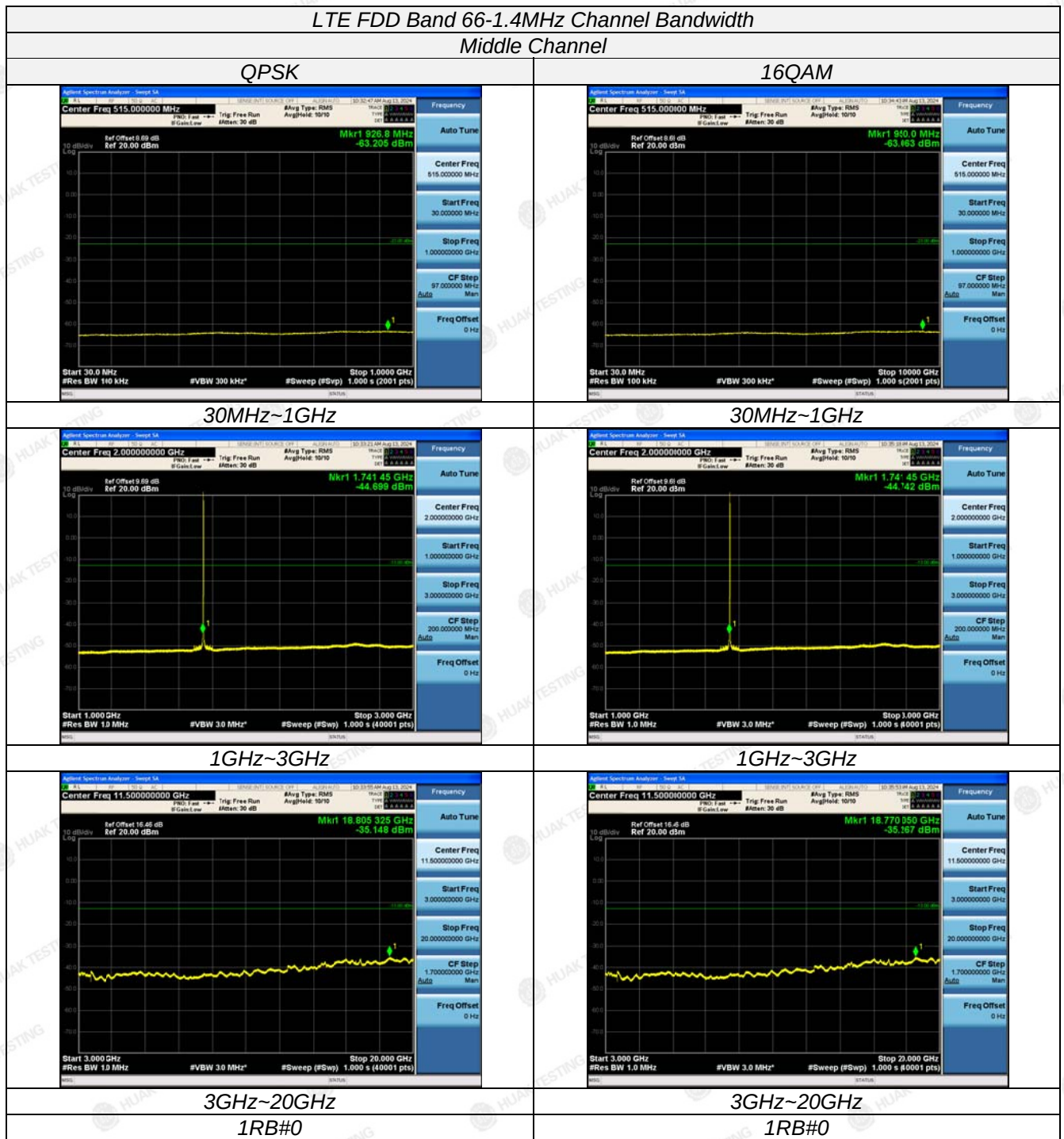
TEST RESULTS

Remark:

- We were tested all RB Configuration refer 3GPP TS136 521 for each Channel Bandwidth of LTE FDD Band 66; recorded worst case for each Channel Bandwidth of LTE FDD Band 66.

Conducted Measurement:

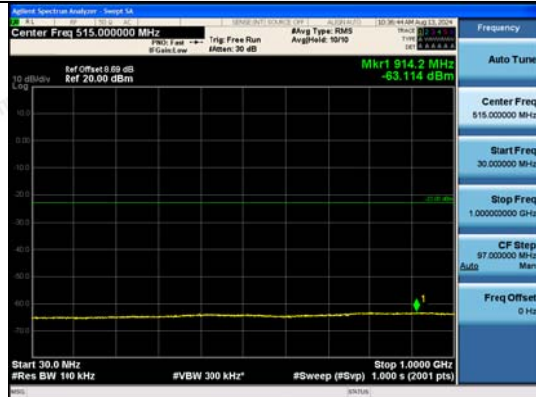




LTE FDD Band 66-1.4MHz Channel Bandwidth
High Channel

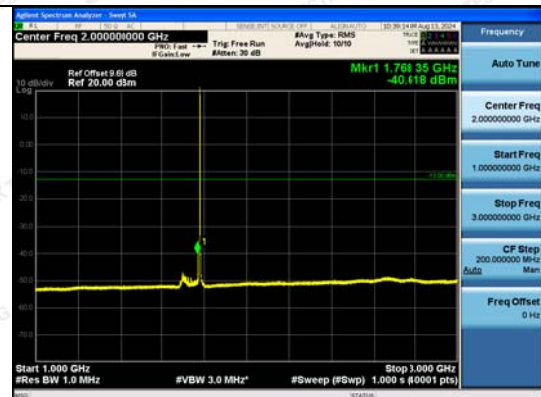
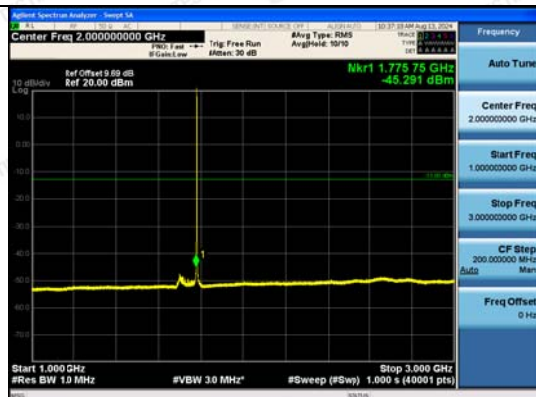
QPSK

16QAM



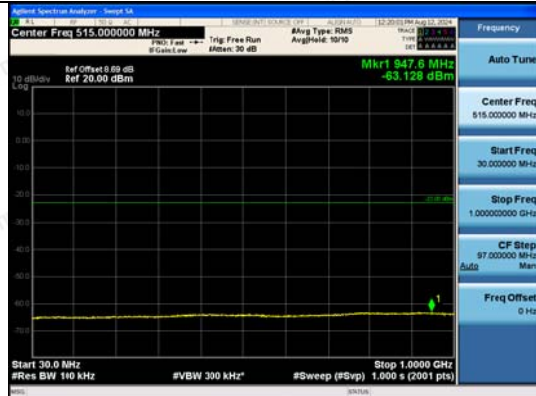
30MHz~1GHz

30MHz~1GHz



1GHz~3GHz

1GHz~3GHz

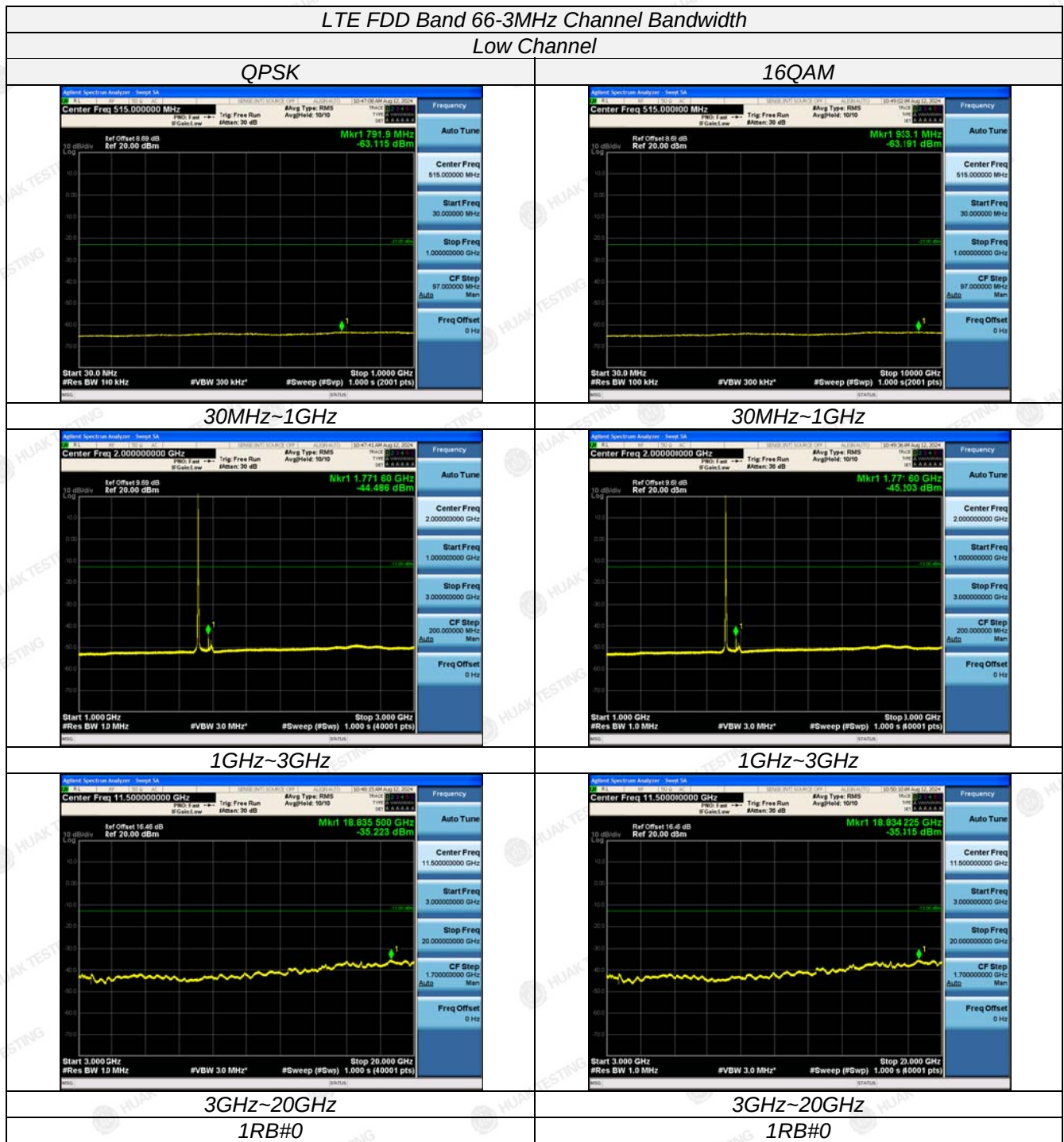


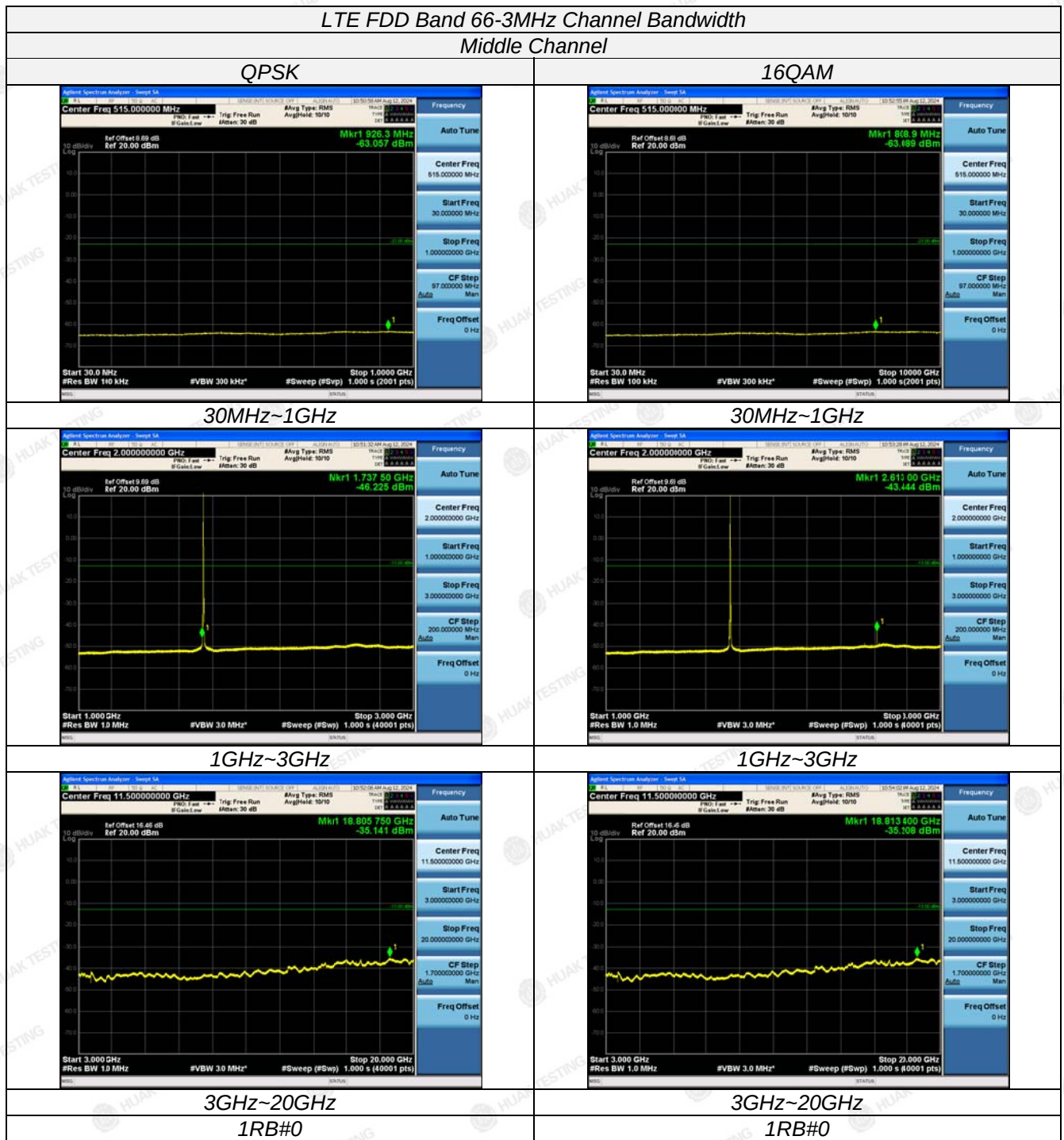
3GHz~20GHz

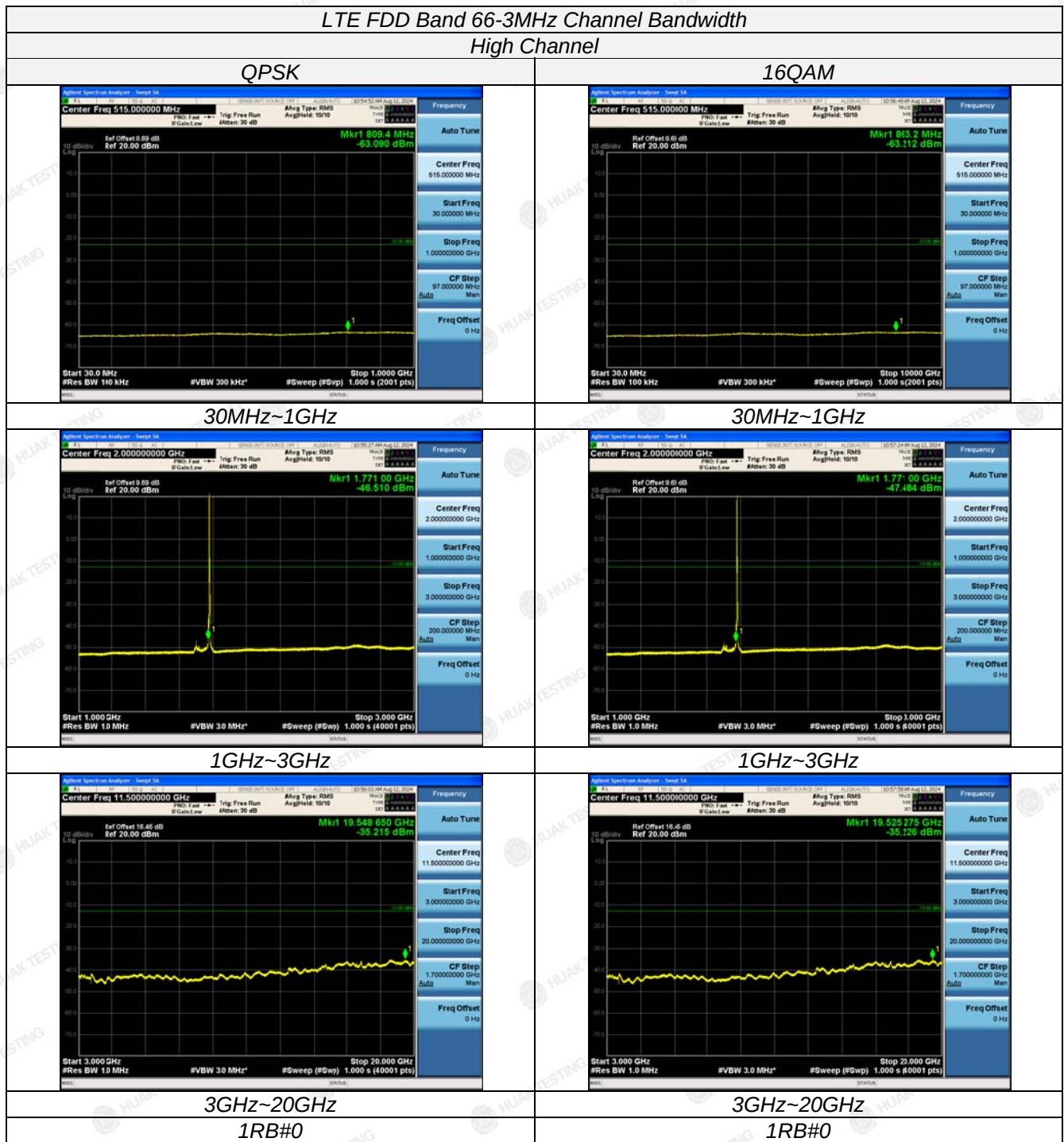
3GHz~20GHz

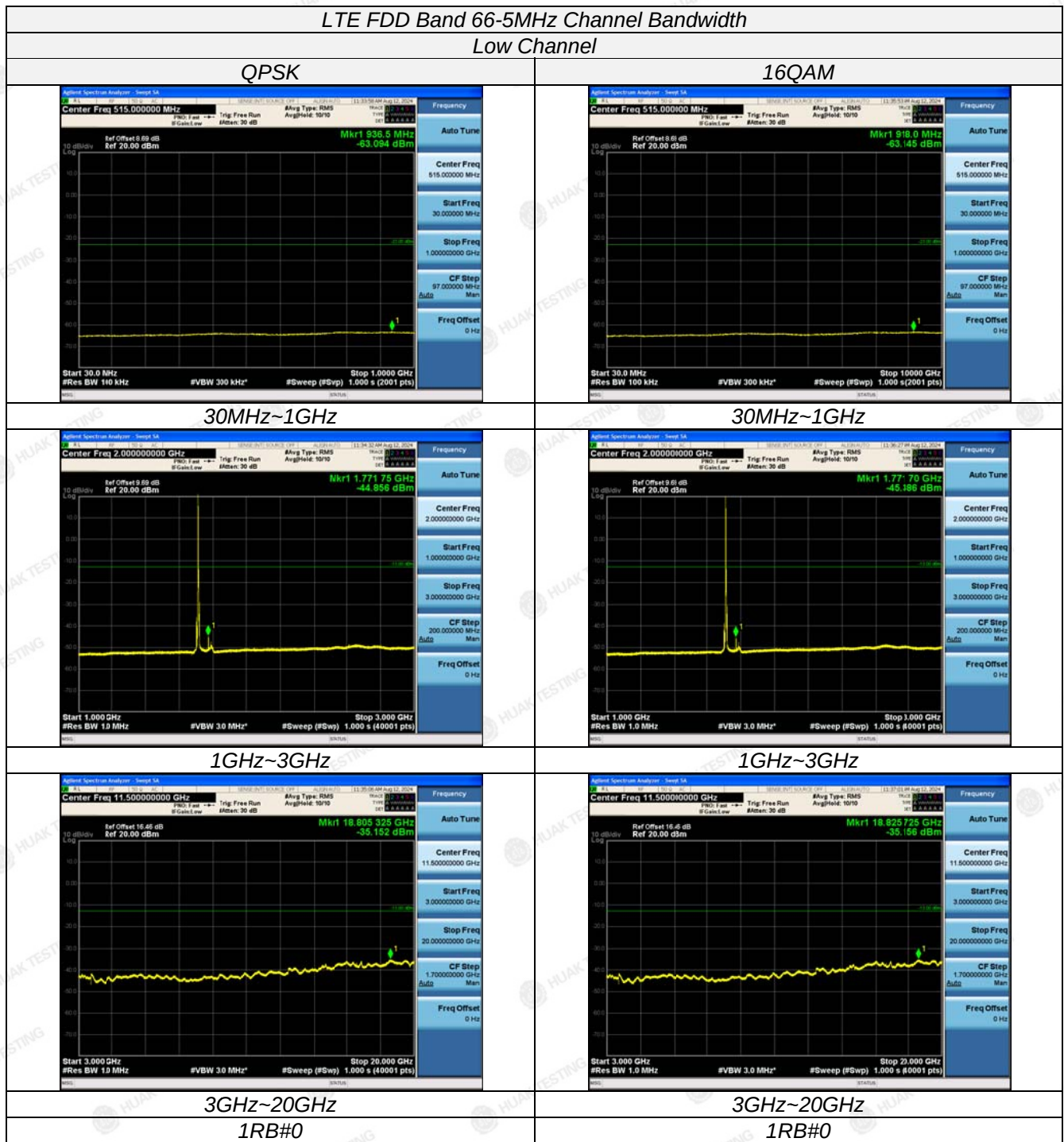
1RB#0

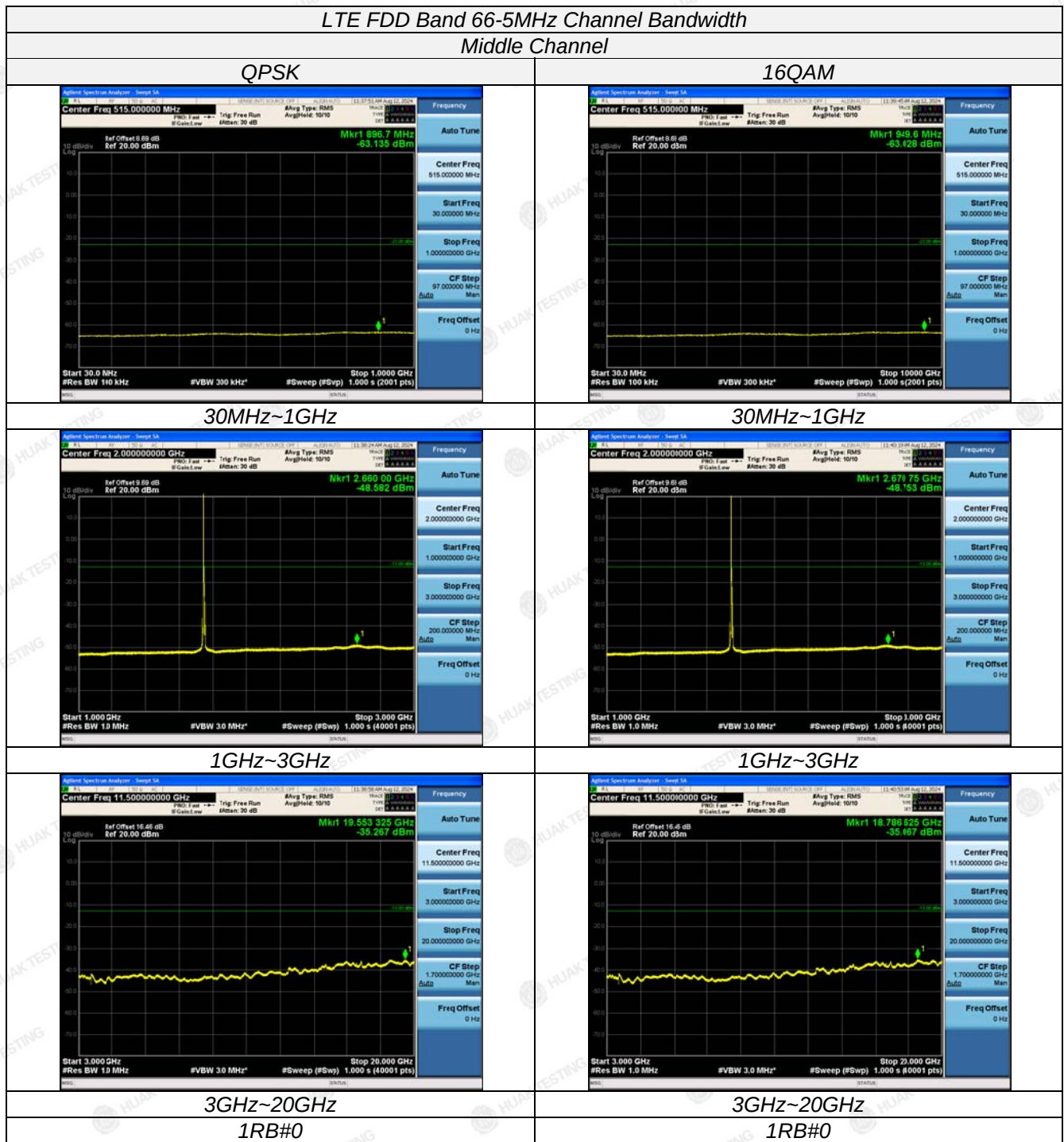
1RB#0

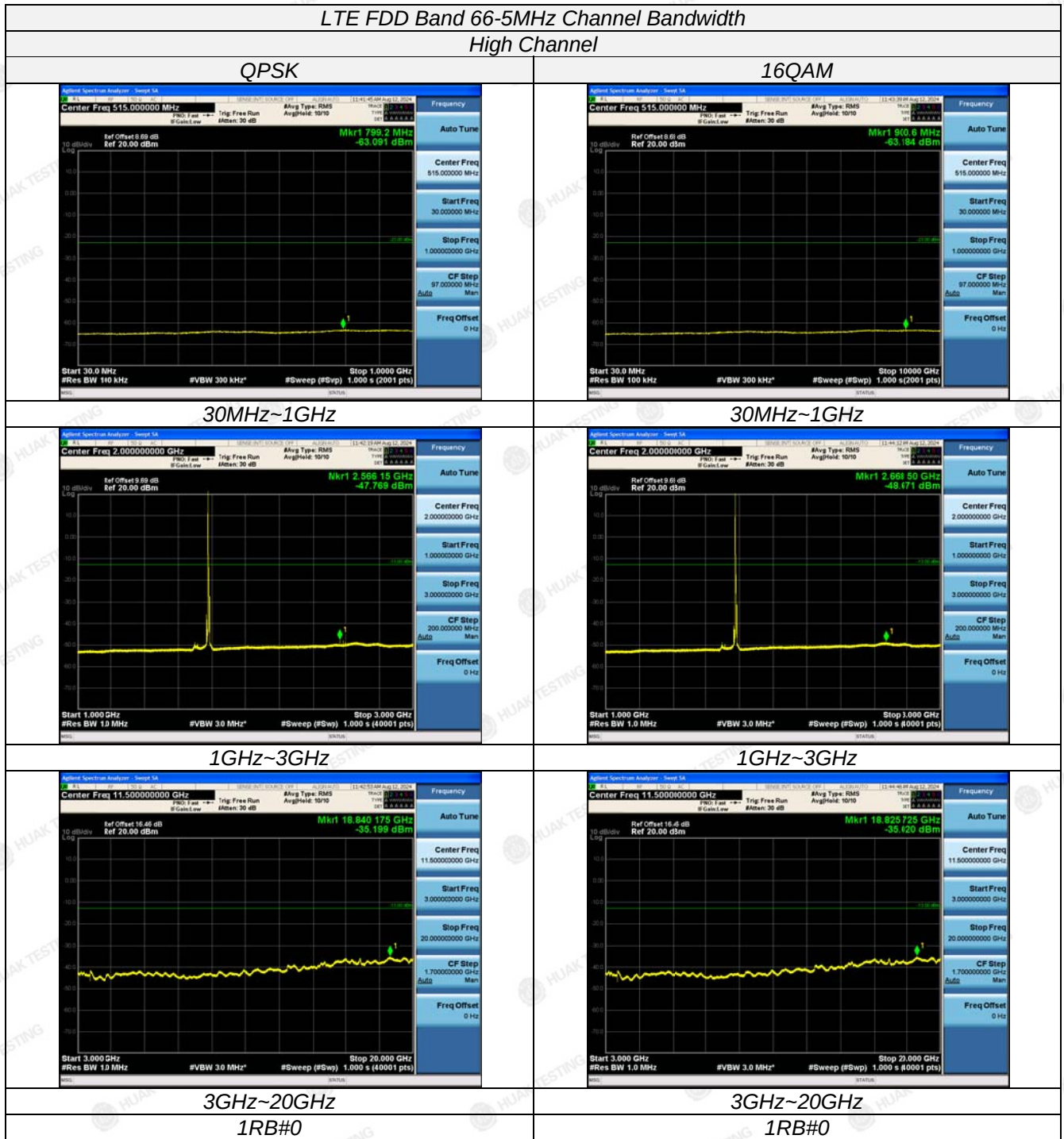








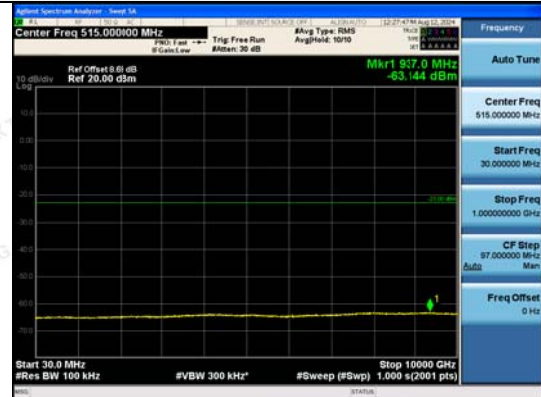
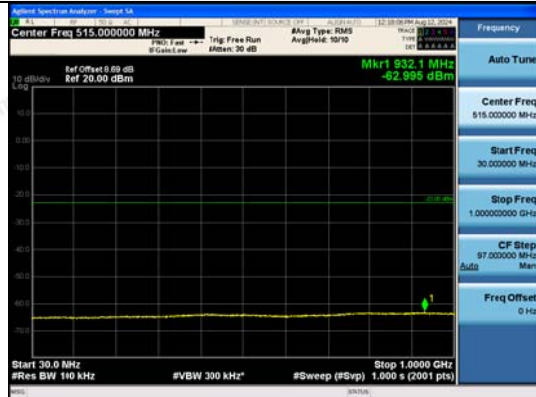




LTE FDD Band 66-10MHz Channel Bandwidth
Low Channel

QPSK

16QAM



30MHz~1GHz

30MHz~1GHz



1GHz~3GHz

1GHz~3GHz

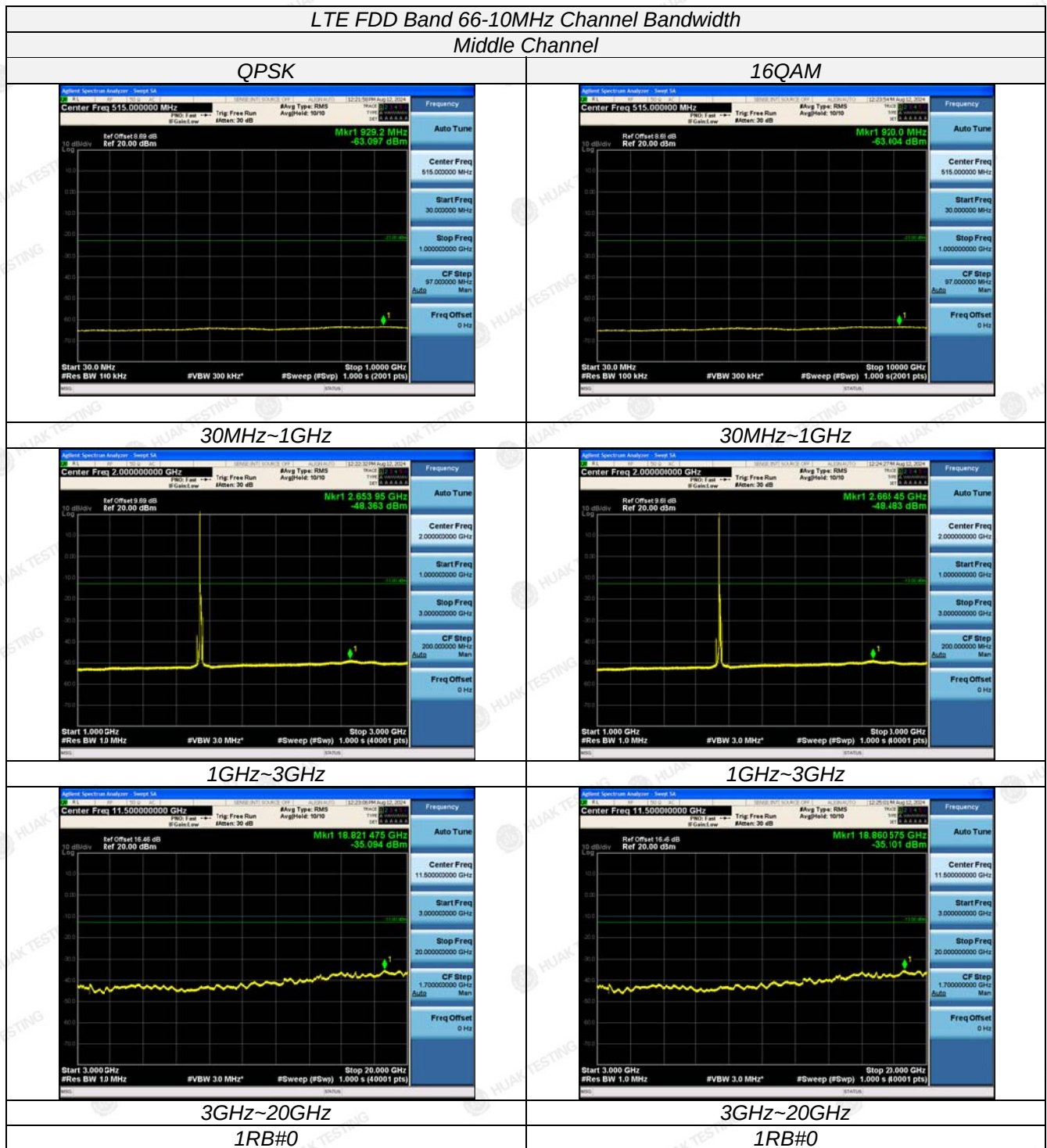


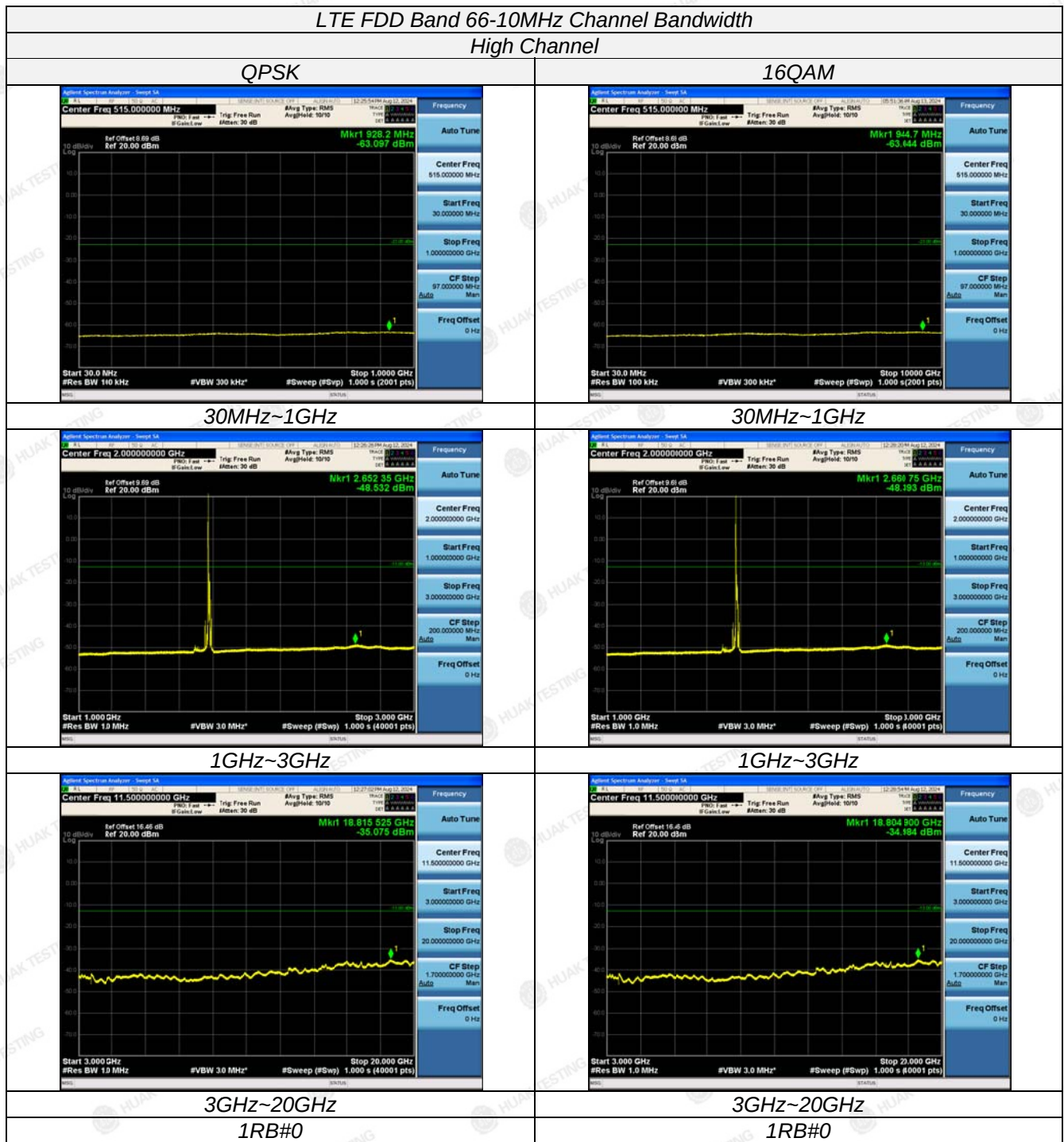
3GHz~20GHz

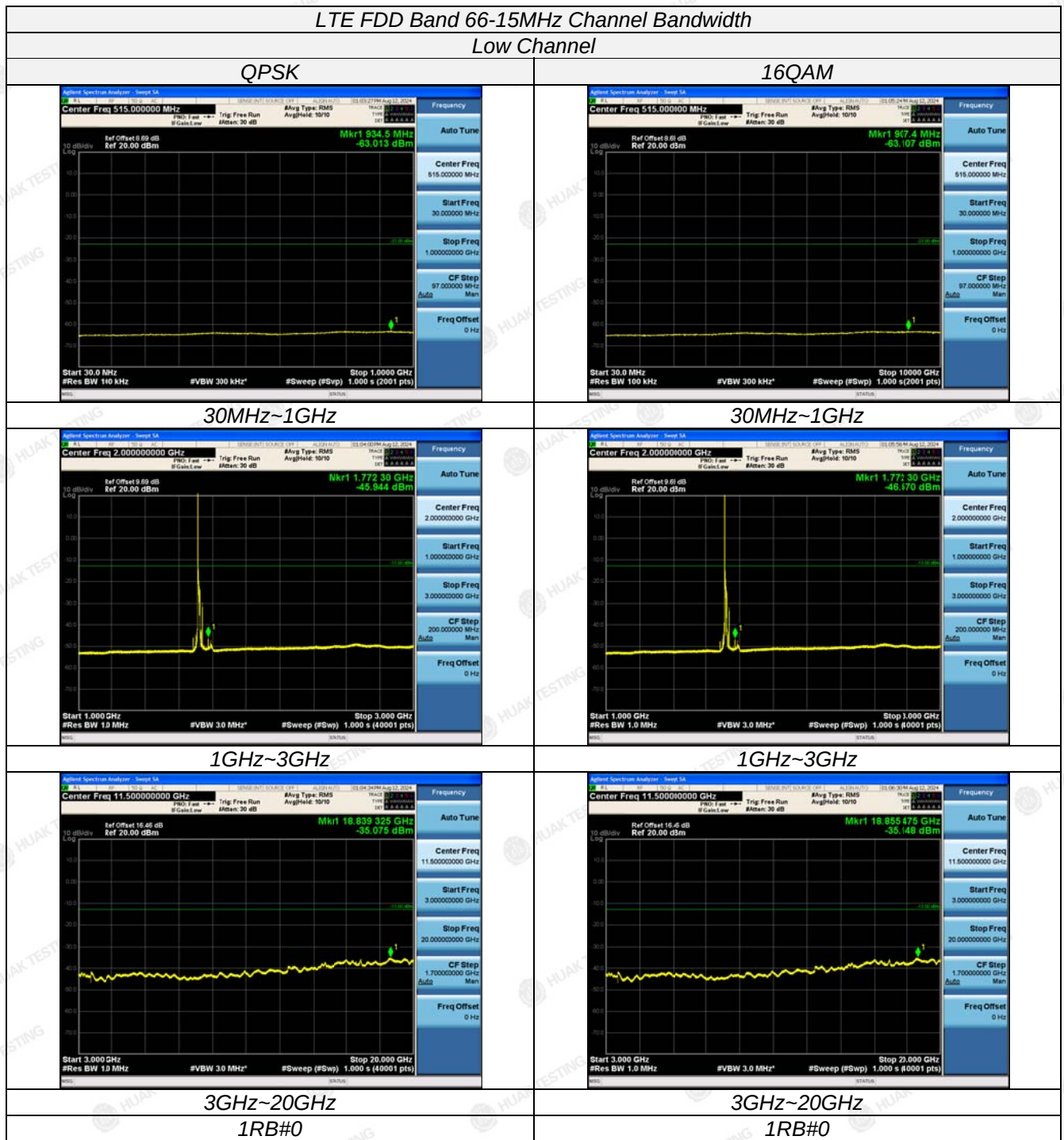
3GHz~20GHz

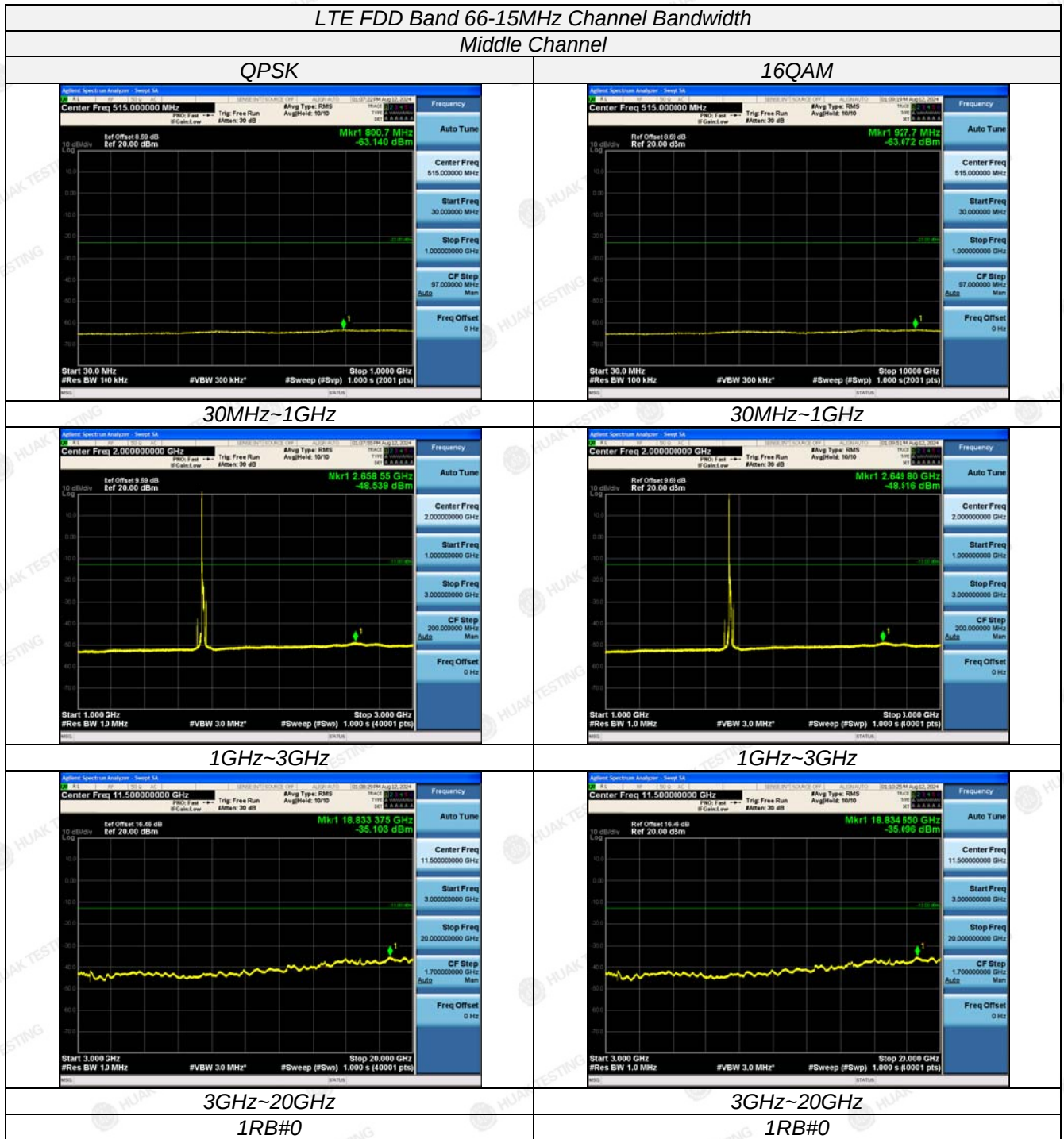
1RB#0

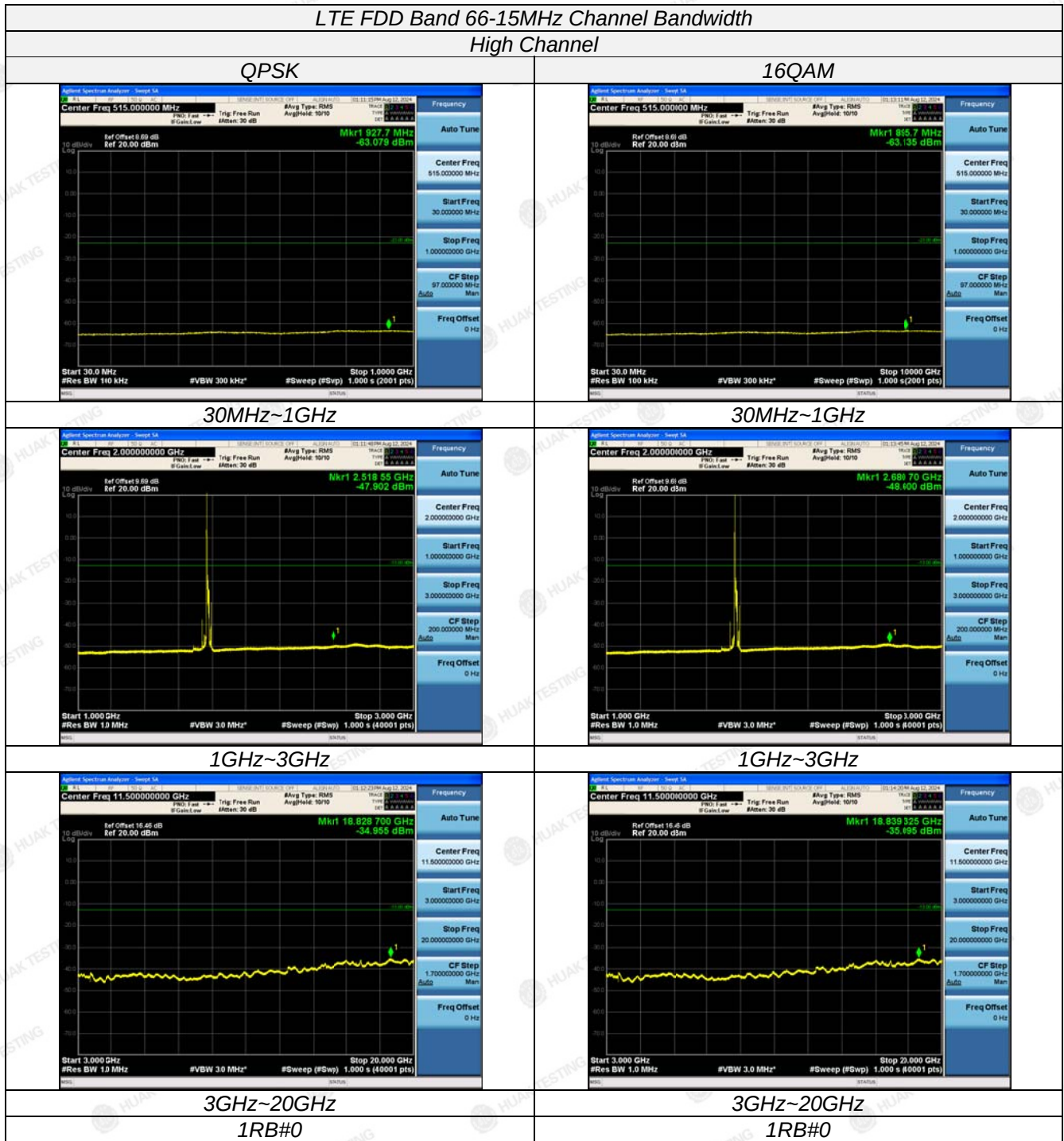
1RB#0







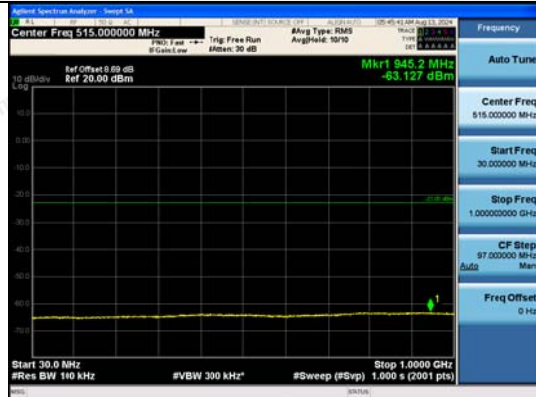




LTE FDD Band 66-20MHz Channel Bandwidth
Low Channel

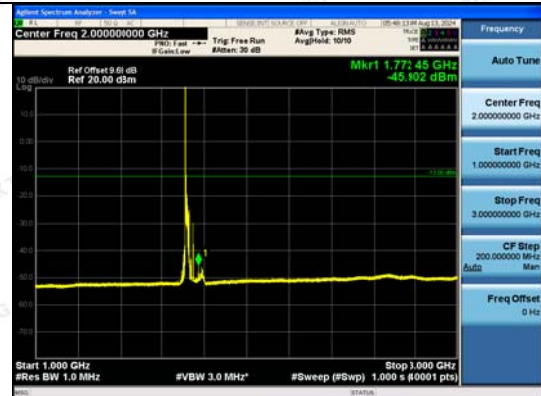
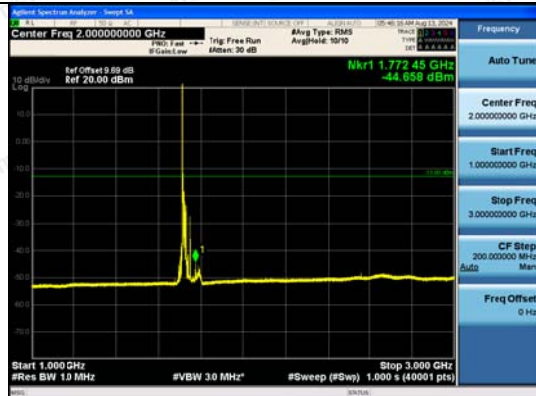
QPSK

16QAM



30MHz~1GHz

30MHz~1GHz



1GHz~3GHz

1GHz~3GHz

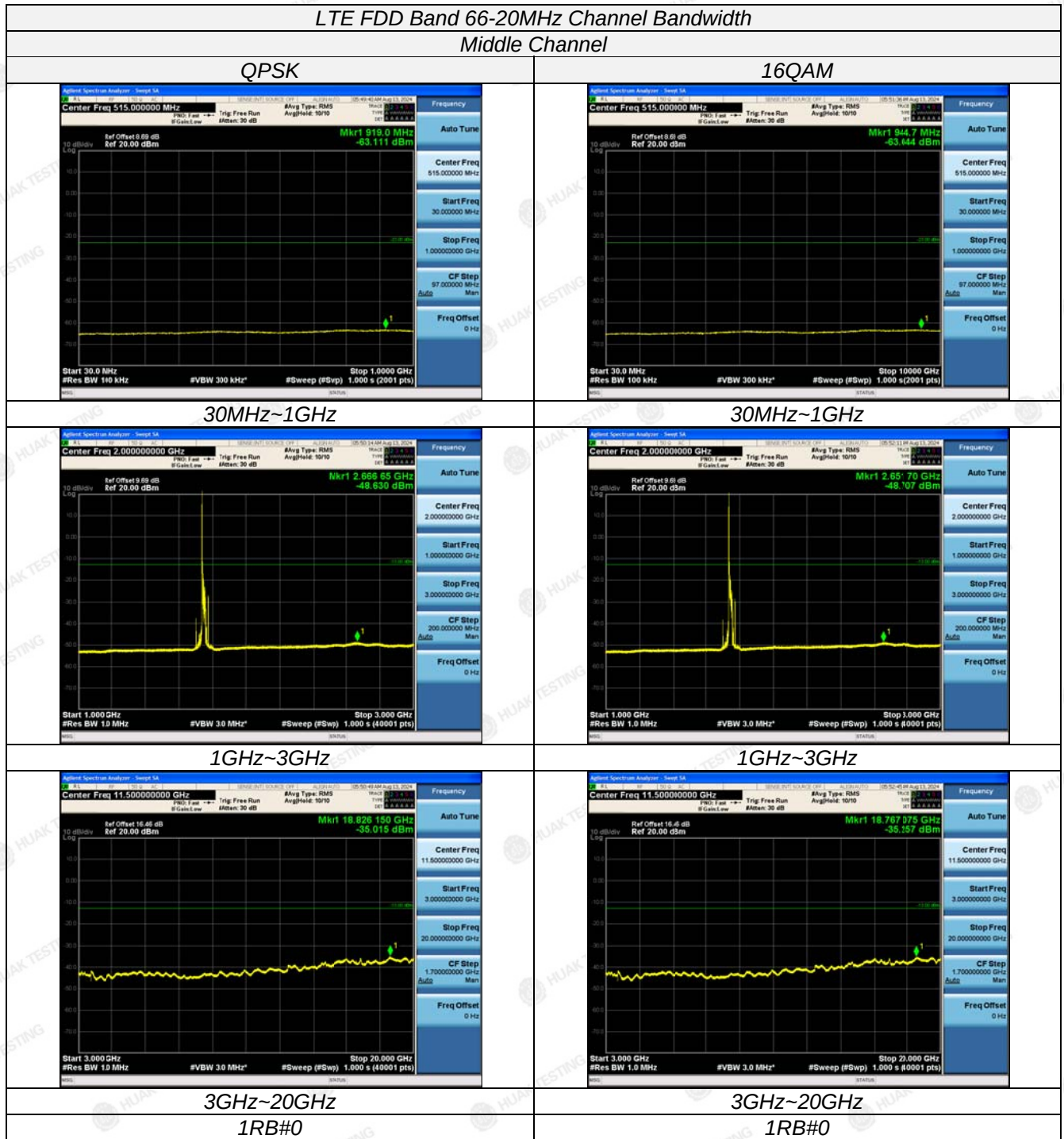


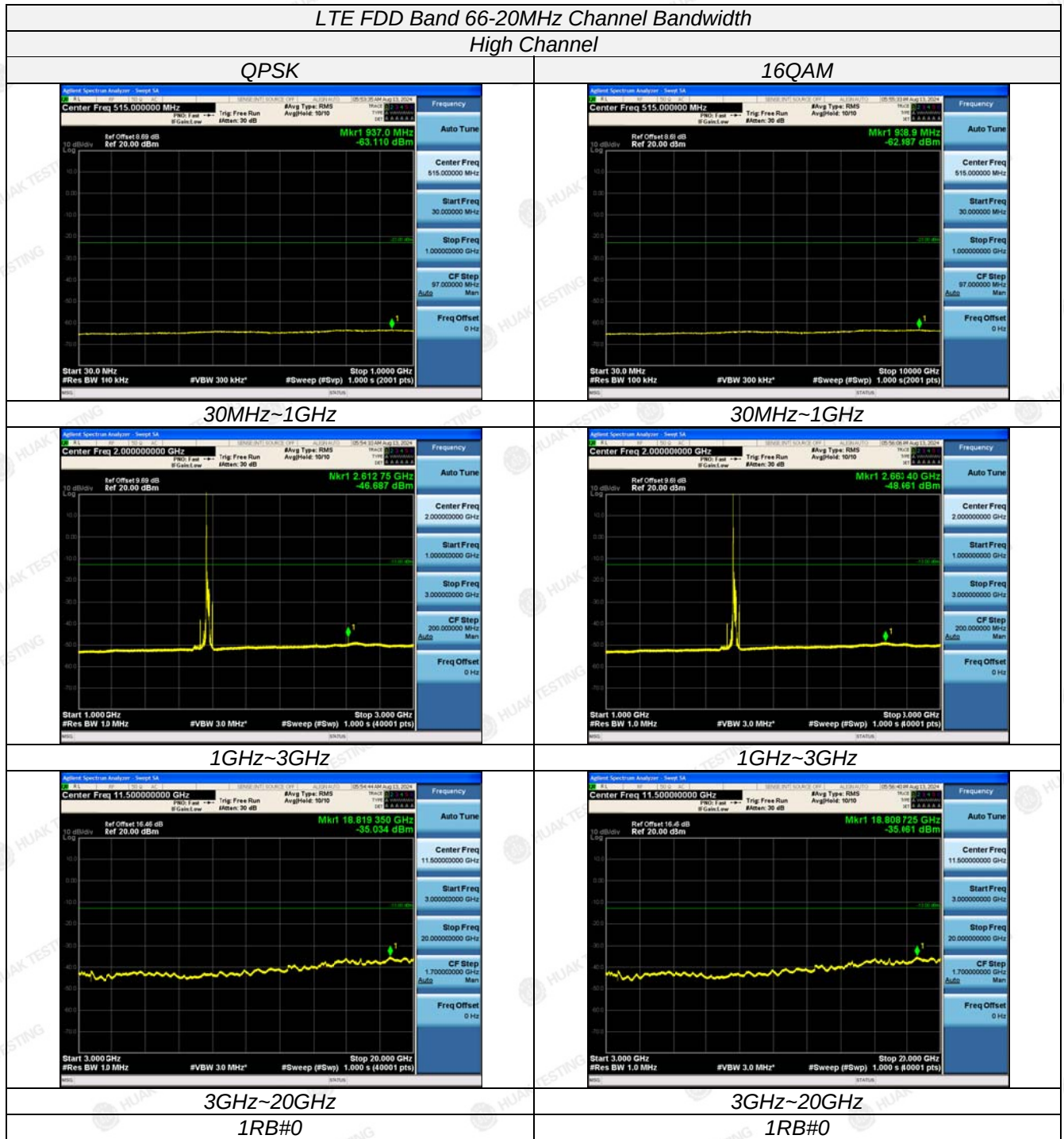
3GHz~20GHz

3GHz~20GHz

1RB#0

1RB#0





**Radiated Measurement:****Remark:**

1. We were tested all RB Configuration refer 3GPP TS136 521 for each Channel Bandwidth of LTE FDD Band 66; recorded worst case for each Channel Bandwidth of LTE FDD Band 66.
2. $EIRP = P_{Mea}(dBm) - P_{cl}(dB) + G_a(dBi)$
3. We were not recorded other points as values lower than limits.
4. $Margin = Limit - EIRP$

LTE FDD Band 66_Channel Bandwidth 1.4MHz_QPSK_Low Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3421.4	-43.15	4.02	3.00	12.5	-34.67	-13.00	21.67	H
5132.1	-48.92	5.11	3.00	13.38	-40.65	-13.00	27.65	H
3421.4	-50.13	4.02	3.00	12.5	-41.65	-13.00	28.65	V
5132.1	-49.23	5.11	3.00	13.38	-40.96	-13.00	27.96	V

LTE FDD Band 66_Channel Bandwidth 1.4MHz_QPSK_Middle Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3490	-44.25	4.02	3.00	12.45	-35.82	-13.00	22.82	H
5235	-47.22	5.11	3.00	13.38	-38.95	-13.00	25.95	H
3490	-49.4	4.02	3.00	12.45	-40.97	-13.00	27.97	V
5235	-47.81	5.11	3.00	13.38	-39.54	-13.00	26.54	V

LTE FDD Band 66_Channel Bandwidth 1.4MHz_QPSK_High Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3558.6	-42.5	4.02	3.00	12.21	-34.31	-13.00	21.31	H
5337.9	-47.12	5.11	3.00	13.26	-38.97	-13.00	25.97	H
3558.6	-48.95	4.02	3.00	12.21	-40.76	-13.00	27.76	V
5337.9	-47.82	5.11	3.00	13.26	-39.67	-13.00	26.67	V

LTE FDD Band 66_Channel Bandwidth 3MHz_QPSK_Low Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3423.0	-44.94	4.02	3.00	12.5	-36.46	-13.00	23.46	H
5134.5	-48.49	5.11	3.00	13.38	-40.22	-13.00	27.22	H
3423.0	-49.68	4.02	3.00	12.5	-41.2	-13.00	28.2	V
5134.5	-48.52	5.11	3.00	13.38	-40.25	-13.00	27.25	V

LTE FDD Band 66_Channel Bandwidth 3MHz_QPSK_Middle Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3490	-44.15	4.02	3.00	12.45	-35.72	-13.00	22.72	H
5235	-47.79	5.11	3.00	13.38	-39.52	-13.00	26.52	H
3490	-49.53	4.02	3.00	12.45	-41.1	-13.00	28.1	V
5235	-47.86	5.11	3.00	13.38	-39.59	-13.00	26.59	V



LTE FDD Band 66 Channel Bandwidth 3MHz_QPSK_High Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3557	-43.2	4.02	3.00	12.21	-35.01	-13.00	22.01	H
5335.5	-46.77	5.11	3.00	13.26	-38.62	-13.00	25.62	H
3557	-49.08	4.02	3.00	12.21	-40.89	-13.00	27.89	V
5335.5	-47.9	5.11	3.00	13.26	-39.75	-13.00	26.75	V

LTE FDD Band 66 Channel Bandwidth 5MHz_QPSK_Low Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3425.0	-45.13	4.02	3.00	12.5	-36.65	-13.00	23.65	H
5137.5	-49.74	5.11	3.00	13.38	-41.47	-13.00	28.47	H
3425.0	-51.31	4.02	3.00	12.5	-42.83	-13.00	29.83	V
5137.5	-49.95	5.11	3.00	13.38	-41.68	-13.00	28.68	V

LTE FDD Band 66 Channel Bandwidth 5MHz_QPSK_Middle Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3490	-43.96	4.02	3.00	12.45	-35.53	-13.00	22.53	H
5235	-47.81	5.11	3.00	13.38	-39.54	-13.00	26.54	H
3490	-50.02	4.02	3.00	12.45	-41.59	-13.00	28.59	V
5235	-47.88	5.11	3.00	13.38	-39.61	-13.00	26.61	V

LTE FDD Band 66 Channel Bandwidth 5MHz_QPSK_High Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3555	-42.5	4.02	3.00	12.21	-34.31	-13.00	21.31	H
5332.5	-46.61	5.11	3.00	13.26	-38.46	-13.00	25.46	H
3555	-48.64	4.02	3.00	12.21	-40.45	-13.00	27.45	V
5332.5	-48.08	5.11	3.00	13.26	-39.93	-13.00	26.93	V

LTE FDD Band 66 Channel Bandwidth 10MHz_QPSK_Low Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3430.0	-44.24	4.02	3.00	12.5	-35.76	-13.00	22.76	H
5145.0	-47.97	5.11	3.00	13.38	-39.7	-13.00	26.7	H
3430.0	-50.92	4.02	3.00	12.5	-42.44	-13.00	29.44	V
5145.0	-47.25	5.11	3.00	13.38	-38.98	-13.00	25.98	V

LTE FDD Band 66 Channel Bandwidth 10MHz_QPSK_Middle Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3490	-44.07	4.02	3.00	12.45	-35.64	-13.00	22.64	H
5235	-47.93	5.11	3.00	13.38	-39.66	-13.00	26.66	H
3490	-49.44	4.02	3.00	12.45	-41.01	-13.00	28.01	V
5235	-47.52	5.11	3.00	13.38	-39.25	-13.00	26.25	V



LTE FDD Band 66_Channel Bandwidth 10MHz_QPSK_High Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3550	-42.9	4.02	3.00	12.21	-34.71	-13.00	21.71	H
5325	-46.88	5.11	3.00	13.26	-38.73	-13.00	25.73	H
3550	-49.01	4.02	3.00	12.21	-40.82	-13.00	27.82	V
5325	-48.49	5.11	3.00	13.26	-40.34	-13.00	27.34	V

LTE FDD Band 66_Channel Bandwidth 15MHz_QPSK_Low Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3435.0	-44.58	4.02	3.00	12.5	-36.1	-13.00	23.1	H
5152.5	-49.7	5.11	3.00	13.38	-41.43	-13.00	28.43	H
3435.0	-49.21	4.02	3.00	12.5	-40.73	-13.00	27.73	V
5152.5	-48.64	5.11	3.00	13.38	-40.37	-13.00	27.37	V

LTE FDD Band 66_Channel Bandwidth 15MHz_QPSK_Middle Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3490	-43.69	4.02	3.00	12.45	-35.26	-13.00	22.26	H
5235	-47.52	5.11	3.00	13.38	-39.25	-13.00	26.25	H
3490	-49.91	4.02	3.00	12.45	-41.48	-13.00	28.48	V
5235	-48	5.11	3.00	13.38	-39.73	-13.00	26.73	V

LTE FDD Band 66_Channel Bandwidth 15MHz_QPSK_High Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3545	-42.67	4.02	3.00	12.21	-34.48	-13.00	21.48	H
5317.5	-46.77	5.11	3.00	13.26	-38.62	-13.00	25.62	H
3545	-48.57	4.02	3.00	12.21	-40.38	-13.00	27.38	V
5317.5	-48.28	5.11	3.00	13.26	-40.13	-13.00	27.13	V

LTE FDD Band 66_Channel Bandwidth 20MHz_QPSK_Low Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3440.0	-43.28	4.02	3.00	12.5	-34.8	-13.00	21.8	H
5160.0	-48.19	5.11	3.00	13.38	-39.92	-13.00	26.92	H
3440.0	-49.52	4.02	3.00	12.5	-41.04	-13.00	28.04	V
5160.0	-48	5.11	3.00	13.38	-39.73	-13.00	26.73	V

LTE FDD Band 66_Channel Bandwidth 20MHz_QPSK_Middle Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3490	-44.25	4.02	3.00	12.45	-35.82	-13.00	22.82	H
5235	-47.77	5.11	3.00	13.38	-39.5	-13.00	26.5	H
3490	-49.75	4.02	3.00	12.45	-41.32	-13.00	28.32	V
5235	-47.3	5.11	3.00	13.38	-39.03	-13.00	26.03	V



LTE FDD Band 66_Channel Bandwidth 20MHz_QPSK_High Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3540	-42.88	4.02	3.00	12.21	-34.69	-13.00	21.69	H
5310	-47.25	5.11	3.00	13.26	-39.1	-13.00	26.1	H
3540	-48.37	4.02	3.00	12.21	-40.18	-13.00	27.18	V
5310	-48.21	5.11	3.00	13.26	-40.06	-13.00	27.06	V

LTE FDD Band 66_Channel Bandwidth 1.4MHz_16QAM_Low Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3421.4	-42.9	4.02	3.00	12.5	-34.42	-13.00	21.42	H
5132.1	-47.71	5.11	3.00	13.38	-39.44	-13.00	26.44	H
3421.4	-50.01	4.02	3.00	12.5	-41.53	-13.00	28.53	V
5132.1	-47.27	5.11	3.00	13.38	-39	-13.00	26	V

LTE FDD Band 66_Channel Bandwidth 1.4MHz_16QAM_Middle Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3490	-43.97	4.02	3.00	12.45	-35.54	-13.00	22.54	H
5235	-47.23	5.11	3.00	13.38	-38.96	-13.00	25.96	H
3490	-50	4.02	3.00	12.45	-41.57	-13.00	28.57	V
5235	-48.09	5.11	3.00	13.38	-39.82	-13.00	26.82	V

LTE FDD Band 66_Channel Bandwidth 1.4MHz_16QAM_High Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3558.6	-42.69	4.02	3.00	12.21	-34.5	-13.00	21.5	H
5337.9	-46.5	5.11	3.00	13.26	-38.35	-13.00	25.35	H
3558.6	-48.45	4.02	3.00	12.21	-40.26	-13.00	27.26	V
5337.9	-48.5	5.11	3.00	13.26	-40.35	-13.00	27.35	V

LTE FDD Band 66_Channel Bandwidth 3MHz_16QAM_Low Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3423.0	-43.71	4.02	3.00	12.5	-35.23	-13.00	22.23	H
5134.5	-49.43	5.11	3.00	13.38	-41.16	-13.00	28.16	H
3423.0	-51.04	4.02	3.00	12.5	-42.56	-13.00	29.56	V
5134.5	-47.61	5.11	3.00	13.38	-39.34	-13.00	26.34	V

LTE FDD Band 66_Channel Bandwidth 3MHz_16QAM_Middle Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3490	-44.35	4.02	3.00	12.45	-35.92	-13.00	22.92	H
5235	-47.3	5.11	3.00	13.38	-39.03	-13.00	26.03	H
3490	-49.68	4.02	3.00	12.45	-41.25	-13.00	28.25	V
5235	-47.94	5.11	3.00	13.38	-39.67	-13.00	26.67	V



LTE FDD Band 66_Channel Bandwidth 3MHz_16QAM_High Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3557	-42.63	4.02	3.00	12.21	-34.44	-13.00	21.44	H
5335.5	-46.93	5.11	3.00	13.26	-38.78	-13.00	25.78	H
3557	-48.93	4.02	3.00	12.21	-40.74	-13.00	27.74	V
5335.5	-48.07	5.11	3.00	13.26	-39.92	-13.00	26.92	V

LTE FDD Band 66_Channel Bandwidth 5MHz_16QAM_Low Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3425.0	-44.36	4.02	3.00	12.5	-35.88	-13.00	22.88	H
5137.5	-48.16	5.11	3.00	13.38	-39.89	-13.00	26.89	H
3425.0	-50.25	4.02	3.00	12.5	-41.77	-13.00	28.77	V
5137.5	-48.27	5.11	3.00	13.38	-40	-13.00	27	V

LTE FDD Band 66_Channel Bandwidth 5MHz_16QAM_Middle Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3490	-44.39	4.02	3.00	12.45	-35.96	-13.00	22.96	H
5235	-47.11	5.11	3.00	13.38	-38.84	-13.00	25.84	H
3490	-50.03	4.02	3.00	12.45	-41.6	-13.00	28.6	V
5235	-48.06	5.11	3.00	13.38	-39.79	-13.00	26.79	V

LTE FDD Band 66_Channel Bandwidth 5MHz_16QAM_High Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3555	-42.8	4.02	3.00	12.21	-34.61	-13.00	21.61	H
5332.5	-46.4	5.11	3.00	13.26	-38.25	-13.00	25.25	H
3555	-49.13	4.02	3.00	12.21	-40.94	-13.00	27.94	V
5332.5	-48.7	5.11	3.00	13.26	-40.55	-13.00	27.55	V

LTE FDD Band 66_Channel Bandwidth 10MHz_16QAM_Low Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3430.0	-44.36	4.02	3.00	12.5	-35.88	-13.00	22.88	H
5145.0	-48.16	5.11	3.00	13.38	-39.89	-13.00	26.89	H
3430.0	-50.25	4.02	3.00	12.5	-41.77	-13.00	28.77	V
5145.0	-48.27	5.11	3.00	13.38	-40	-13.00	27	V

LTE FDD Band 66_Channel Bandwidth 10MHz_16QAM_Middle Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3490	-44.39	4.02	3.00	12.45	-35.96	-13.00	22.96	H
5235	-47.11	5.11	3.00	13.38	-38.84	-13.00	25.84	H
3490	-50.03	4.02	3.00	12.45	-41.6	-13.00	28.6	V
5235	-48.06	5.11	3.00	13.38	-39.79	-13.00	26.79	V



LTE FDD Band 66_Channel Bandwidth 10MHz_16QAM_High Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3550	-42.8	4.02	3.00	12.21	-34.61	-13.00	21.61	H
5325	-46.4	5.11	3.00	13.26	-38.25	-13.00	25.25	H
3550	-49.13	4.02	3.00	12.21	-40.94	-13.00	27.94	V
5325	-48.7	5.11	3.00	13.26	-40.55	-13.00	27.55	V

LTE FDD Band 66_Channel Bandwidth 15MHz_16QAM_Low Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3435.0	-42.9	4.02	3.00	12.5	-34.42	-13.00	21.42	H
5152.5	-49.93	5.11	3.00	13.38	-41.66	-13.00	28.66	H
3435.0	-50.75	4.02	3.00	12.5	-42.27	-13.00	29.27	V
5152.5	-47.19	5.11	3.00	13.38	-38.92	-13.00	25.92	V

LTE FDD Band 66_Channel Bandwidth 15MHz_16QAM_Middle Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3490	-44.24	4.02	3.00	12.45	-35.81	-13.00	22.81	H
5235	-47.43	5.11	3.00	13.38	-39.16	-13.00	26.16	H
3490	-50.03	4.02	3.00	12.45	-41.6	-13.00	28.6	V
5235	-48.11	5.11	3.00	13.38	-39.84	-13.00	26.84	V

LTE FDD Band 66_Channel Bandwidth 15MHz_16QAM_High Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3545	-42.49	4.02	3.00	12.21	-34.3	-13.00	21.3	H
5317.5	-46.34	5.11	3.00	13.26	-38.19	-13.00	25.19	H
3545	-48.96	4.02	3.00	12.21	-40.77	-13.00	27.77	V
5317.5	-47.84	5.11	3.00	13.26	-39.69	-13.00	26.69	V

LTE FDD Band 66_Channel Bandwidth 20MHz_16QAM_Low Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3440.0	-44.44	4.02	3.00	12.5	-35.96	-13.00	22.96	H
5160.0	-49.22	5.11	3.00	13.38	-40.95	-13.00	27.95	H
3440.0	-51.24	4.02	3.00	12.5	-42.76	-13.00	29.76	V
5160.0	-49.28	5.11	3.00	13.38	-41.01	-13.00	28.01	V

LTE FDD Band 66_Channel Bandwidth 20MHz_16QAM_Middle Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3490	-44.44	4.02	3.00	12.45	-36.01	-13.00	23.01	H
5235	-47.88	5.11	3.00	13.38	-39.61	-13.00	26.61	H
3490	-50.03	4.02	3.00	12.45	-41.6	-13.00	28.6	V
5235	-47.25	5.11	3.00	13.38	-38.98	-13.00	25.98	V



LTE FDD Band 66 Channel Bandwidth 20MHz 16QAM High Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3540	-43.16	4.02	3.00	12.21	-34.97	-13.00	21.97	H
5310	-47.05	5.11	3.00	13.26	-38.9	-13.00	25.9	H
3540	-48.93	4.02	3.00	12.21	-40.74	-13.00	27.74	V
5310	-48.03	5.11	3.00	13.26	-39.88	-13.00	26.88	V

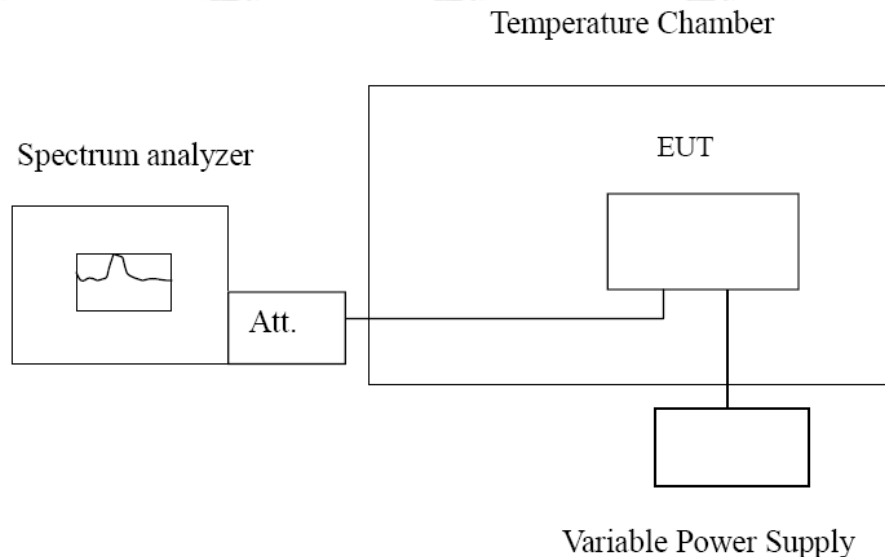


3.6 Frequency Stability under Temperature & Voltage Variations

LIMIT

According to §27.54, §2.1055 requirement, the frequency stability shall be sufficient to ensure that the fundamental emissions stay within the authorized bands of operation and should not exceed 2.5ppm.

TEST CONFIGURATION



TEST PROCEDURE

The EUT was setup according to EIA/TIA 603D.

Frequency Stability Under Temperature Variations:

In order to measure the carrier frequency under the condition of AFC lock, it is necessary to make measurements with the EUT in a "call mode". This is accomplished with the use of R&S CMW500 DIGITAL RADIO COMMUNICATION TESTER.

1. Measure the carrier frequency at room temperature.
2. Subject the EUT to overnight soak at -30°C.
3. With the EUT, powered via nominal voltage, connected to the CMW500 and in a simulated call on middle channel for LTE band 4, measure the carrier frequency. These measurements should be made within 2 minutes of Powering up the EUT, to prevent significant self-warming.
4. Repeat the above measurements at 10°C increments from -30°C to +50°C. Allow at least 1.5 hours at each temperature, unpowered, before making measurements.
5. Re-measure carrier frequency at room temperature with nominal voltage. Vary supply voltage from minimum voltage to maximum voltage, in 0.1Volt increments re-measuring carrier frequency at each voltage. Pause at nominal voltage for 1.5 hours unpowered, to allow any self-heating to stabilize, before continuing.
6. Subject the EUT to overnight soak at +50°C.
7. With the EUT, powered via nominal voltage, connected to the CMW500 and in a simulated call on the centre channel, measure the carrier frequency. These measurements should be made within 2 minutes of Powering up the EUT, to prevent significant self-warming.
8. Repeat the above measurements at 10 °C increments from +50°C to -30°C. Allow at least 1.5 hours at each temperature, unpowered, before making measurements.
9. At all temperature levels hold the temperature to +/- 0.5°C during the measurement procedure.

Frequency Stability Under Voltage Variations:

Set chamber temperature to 20°C. Use a variable AC power supply / DC power source to power the EUT and set the voltage to rated voltage. Set the spectrum analyzer RBW low enough to obtain the desired frequency resolution and recorded the frequency.

Reduce the input voltage to specify extreme voltage variation ($\pm 15\%$) and endpoint, record the maximum frequency change.

**TEST RESULTS**

Remark:

1. We tested all RB Configuration refer 3GPP TS136 521 for each Channel Bandwidth of LTE FDD Band 66; recorded worst case.

LTE Band 66, 1.4MHz bandwidth , QPSK (worst case of all bandwidths)

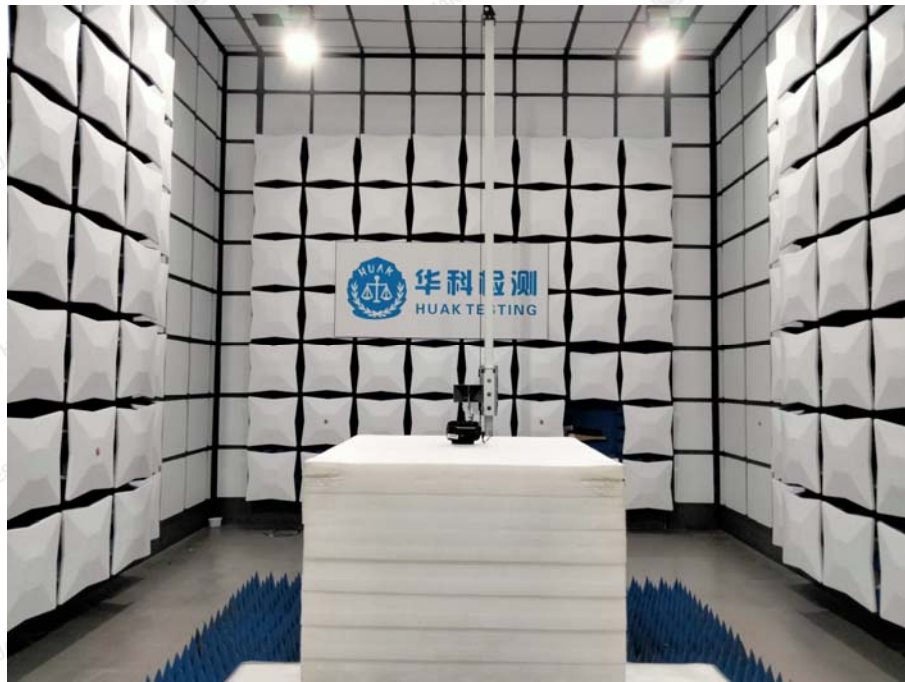
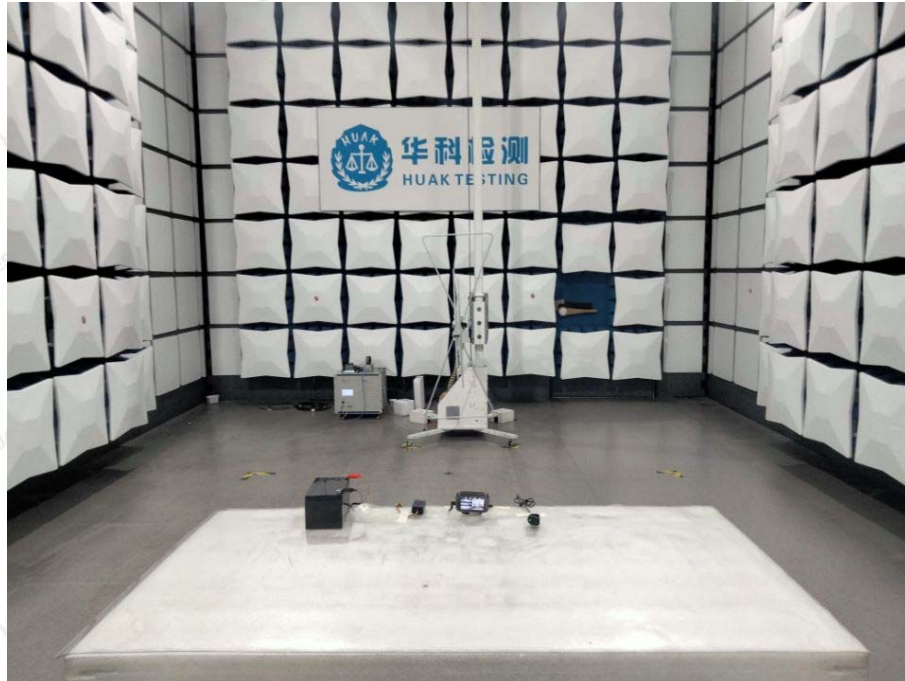
LTE FDD Band 66				
DC Power	Temperature (°C)	Frequency error(Hz)	Frequency error(ppm)	Verdict
4.25	20	-22.50	-0.012894	PASS
5.0	20	-24.81	-0.014218	PASS
5.75	20	-23.88	-0.013685	PASS
5.0	-30	-24.78	-0.014201	PASS
5.0	-20	-20.94	-0.012000	PASS
5.0	-10	-26.22	-0.015026	PASS
5.0	0	-10.93	-0.006264	PASS
5.0	10	-9.13	-0.005232	PASS
5.0	20	3.35	0.001920	PASS
5.0	30	6.14	0.003519	PASS
5.0	40	9.27	0.005312	PASS
5.0	50	18.32	0.010499	PASS

LTE Band 66, 1.4MHz bandwidth , 16QAM (worst case of all bandwidths)

LTE FDD Band 66				
DC Power	Temperature (°C)	Frequency error(Hz)	Frequency error(ppm)	Verdict
4.25	20	21.73	0.012453	PASS
5.0	20	29.33	0.016808	PASS
5.75	20	34.62	0.019840	PASS
5.0	-30	21.72	0.012213	PASS
5.0	-20	12.33	0.006933	PASS
5.0	-10	-4.38	-0.002463	PASS
5.0	0	-8.67	-0.004875	PASS
5.0	10	-16.21	-0.009114	PASS
5.0	20	-25.92	-0.014574	PASS
5.0	30	-29.85	-0.016784	PASS
5.0	40	-42.00	-0.023615	PASS
5.0	50	15.08	0.008479	PASS



4 TEST SETUP PHOTOS OF THE EUT



The results shown in this test report refer only to the sample(s) tested unless otherwise stated and the sample(s) are retained for 30 days only. The document is issued by HUAKE, this document cannot be reproduced except in full with our prior written permission. The more details and the authenticity of the report will be confirmed at <http://www.cer-mark.com>.

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5 PHOTOS OF THE EUT

Reference to the report: ANNEX A of external photos and ANNEX B of internal photos.

.....End of Report.....